

# **DATA SHEET**

**BYC5-600**  
**Rectifier diode**  
**Freewheeling and power factor**  
**correction**

Product specification  
File under Discrete Semiconductors, SC02

October 1997

## Rectifier diode

### Freewheeling and power factor correction

BYC5-600

**GENERAL DESCRIPTION**

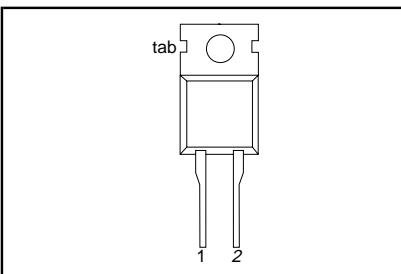
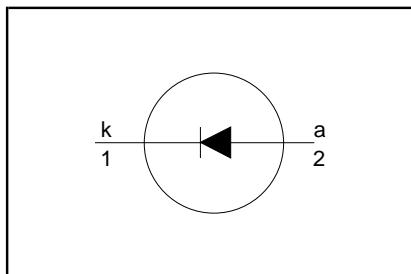
Glass passivated, epitaxial rectifier diode in a plastic envelope. This diode has extremely fast reverse recovery time and low reverse recovery current and is designed specifically for use in forced commutation applications, for example:- as the output rectifier diode in power factor correction circuits operating in continuous conduction mode; or as a freewheeling diode in half-bridge and full-bridge switched mode power supplies.

**QUICK REFERENCE DATA**

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
$I_{F(AV)}$	Average forward current		5	A
$V_{RRM}$	Repetitive peak reverse voltage		600	V
$V_F$	Forward voltage		1.75	V
$t_{rr}$	Reverse recovery time	15	11	ns
$I_{rrm}$	Reverse recovery current			A

**PINNING - TO220AC**

PIN	DESCRIPTION
1	cathode (k)
2	anode (a)
tab	cathode (k)

**PIN CONFIGURATION****SYMBOL****LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	Repetitive peak reverse voltage		-	600	V
$V_{RWM}$	Crest working reverse voltage		-	600	V
$V_R$	Continuous reverse voltage		-	500	V
$I_{F(AV)}$	Average forward current	$T_{mb} \leq 110^\circ\text{C}^1$ $\delta = 0.5$ ; with reapplied $V_{RRM(max)}$ ; $T_{mb} \leq 89^\circ\text{C}^1$	-	5	A
$I_{F(RMS)}$	RMS forward current		-	7	A
$I_{FRM}$	Repetitive peak forward current	$\delta = 0.5$ ; with reapplied $V_{RRM(max)}$ ; $T_{mb} \leq 89^\circ\text{C}^1$	-	10	A
$I_{FSM}$	Non-repetitive peak forward current.	$t = 10 \text{ ms}$ $t = 8.3 \text{ ms}$ sinusoidal; $T_j = 150^\circ\text{C}$ prior to surge with reapplied $V_{RWM(max)}$	-	40	A
$I^2t$	$I^2t$ for fusing		-	8	$\text{A}^2\text{s}$
$T_{stg}$	Storage temperature		-40	150	$^\circ\text{C}$
$T_j$	Operating junction temperature		-	150	$^\circ\text{C}$

<sup>1</sup> Maximum mounting base temperature limited by thermal runaway.

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**THERMAL RESISTANCES**

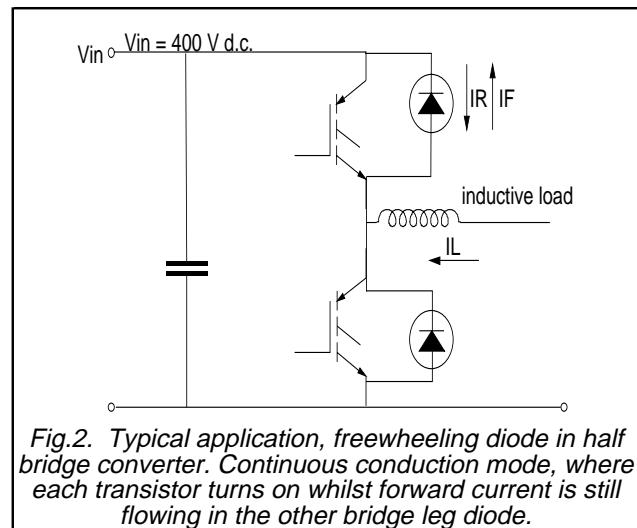
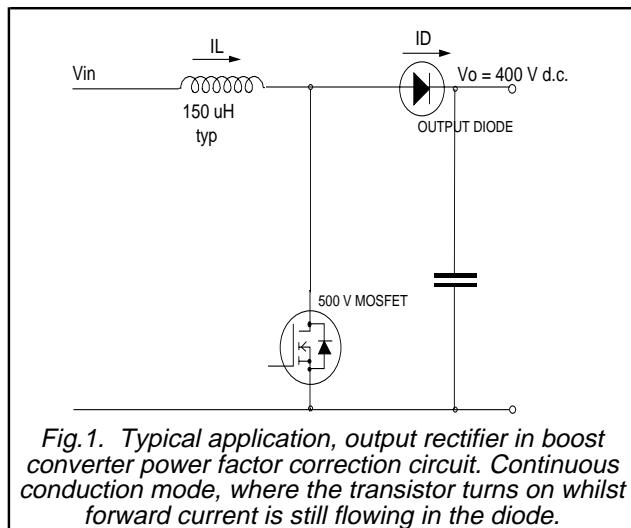
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j\rightarrow mb}$	Thermal resistance junction to mounting base		-	-	2.5	K/W
$R_{th\ j\rightarrow a}$	Thermal resistance junction to ambient	in free air.	-	60	-	K/W

**STATIC CHARACTERISTICS** $T_j = 25^\circ C$  unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_F$	Forward voltage	$I_F = 5 A; T_j = 150^\circ C$ $I_F = 10 A; T_j = 150^\circ C$	-	1.4 1.75	1.75 2.2	V
$I_R$	Reverse current	$I_F = 5 A;$ $V_R = 600 V$ $V_R = 500 V; T_j = 100^\circ C$	-	2.0 9 0.9	2.8 100 3.0	$\mu A$ mA

**DYNAMIC CHARACTERISTICS** $T_j = 25^\circ C$  unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$t_{rr}$	Reverse recovery time	$I_F = 5 A$ to $V_R = 400 V$ ; $dI_F/dt = 500 A/\mu s$	-	19	-	ns
$t_{rr}$	Reverse recovery time	$I_F = 5 A$ to $V_R = 400 V$ ; $dI_F/dt = 500 A/\mu s; T_j = 125^\circ C$	-	25	30	ns
$I_{rrm}$	Peak reverse recovery current	$I_F = 5 A$ to $V_R = 400 V$ ; $dI_F/dt = 500 A/\mu s; T_j = 125^\circ C$	-	8	11	A
$V_{fr}$	Forward recovery voltage	$I_F = 10 A$ ; $dI_F/dt = 100 A/\mu s$	-	9	11	V



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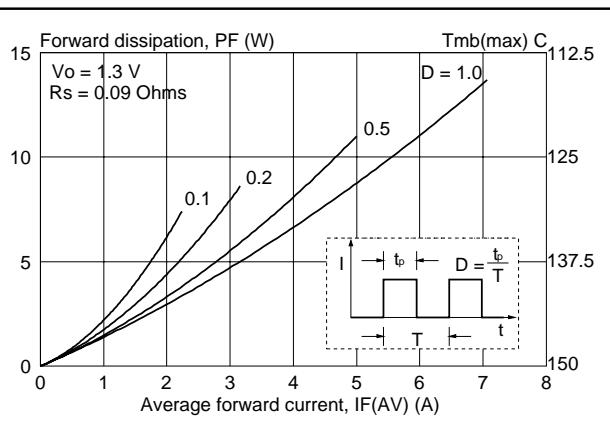


Fig.3. Maximum forward dissipation as a function of average forward current; rectangular current waveform where  $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$ .

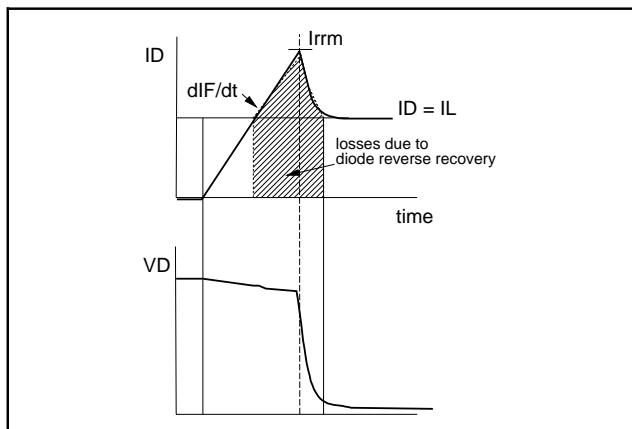


Fig.6. Origin of switching losses in transistor due to diode reverse recovery.

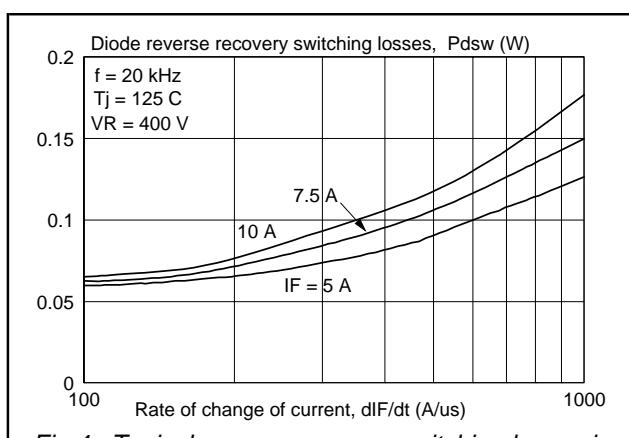


Fig.4. Typical reverse recovery switching losses in diode, as a function of rate of change of current  $dI/dt$ .

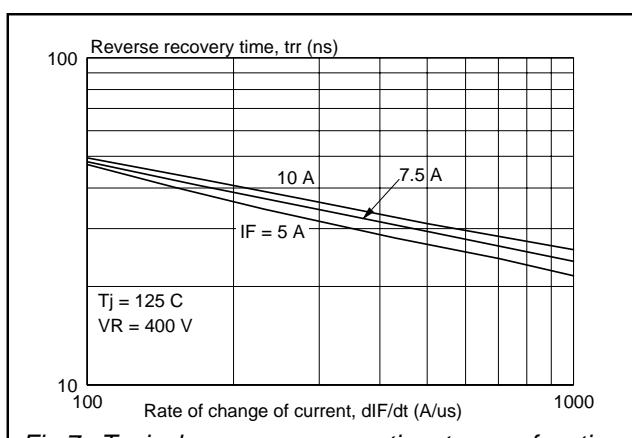


Fig.7. Typical reverse recovery time  $t_{rr}$  as a function of rate of change of current  $dI/dt$ .

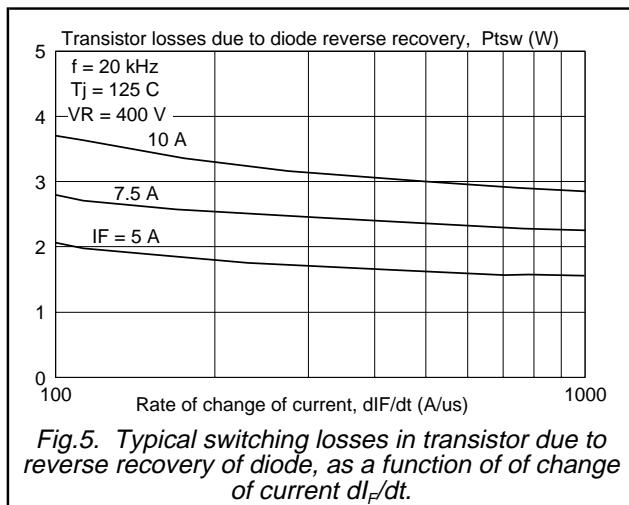


Fig.5. Typical switching losses in transistor due to reverse recovery of diode, as a function of of change of current  $dI/dt$ .

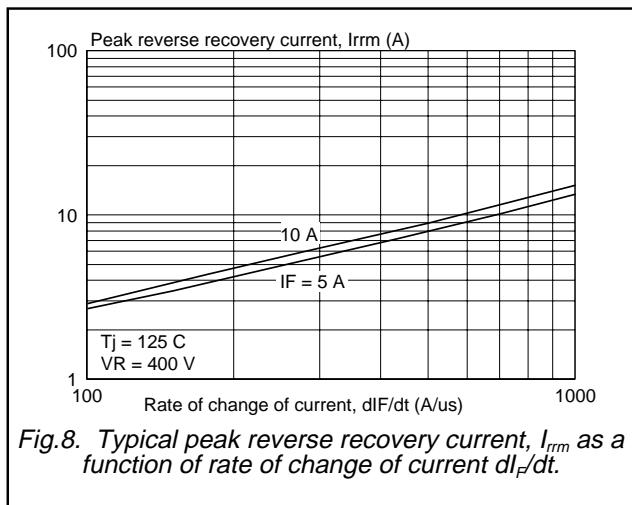
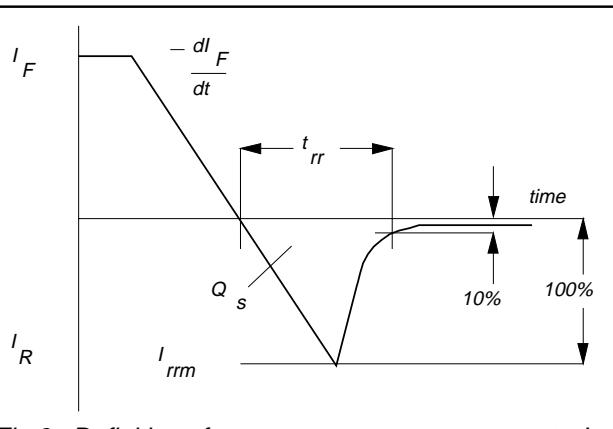
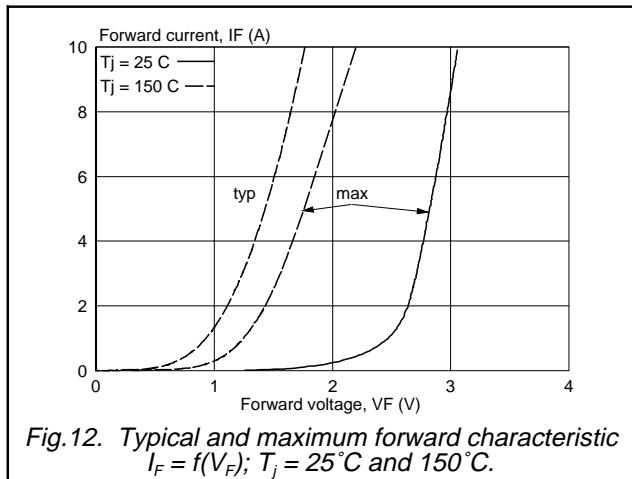
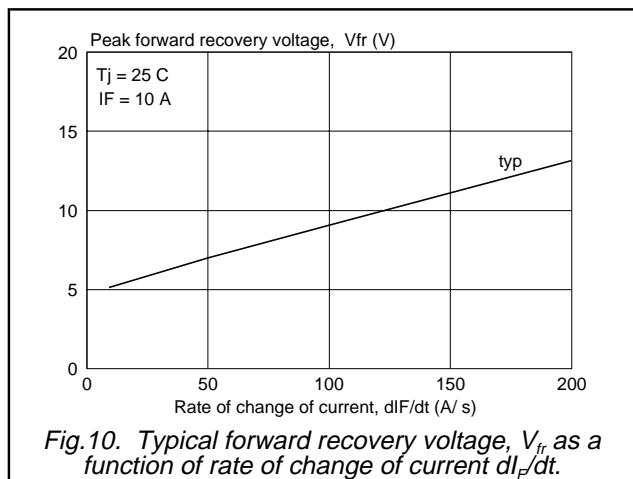
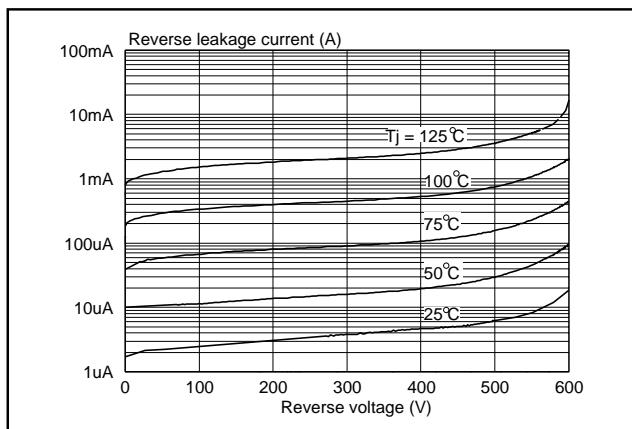
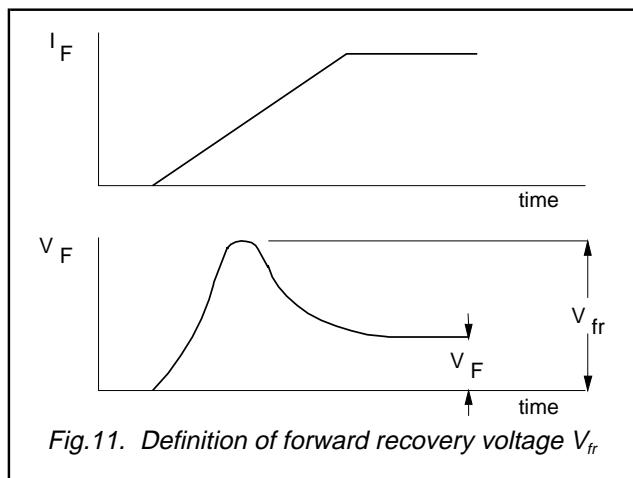
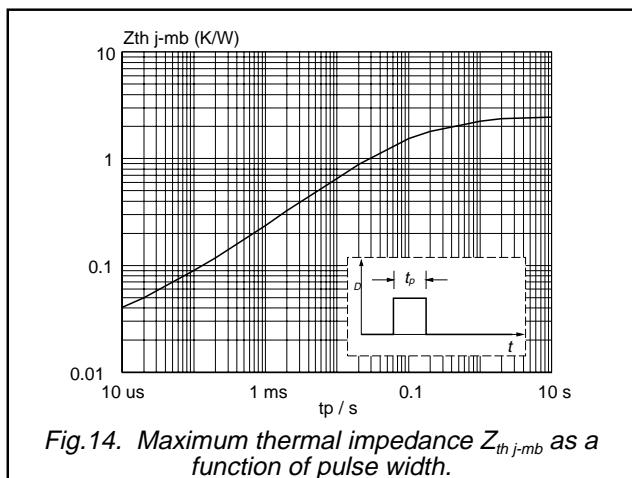


Fig.8. Typical peak reverse recovery current,  $I_{rrm}$  as a function of rate of change of current  $dI/dt$ .

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Fig.9. Definition of reverse recovery parameters  $t_{rr}$ ,  $I_{rrm}$ Fig.12. Typical and maximum forward characteristic  $I_F = f(V_F)$ ;  $T_j = 25^\circ\text{C}$  and  $150^\circ\text{C}$ .Fig.10. Typical forward recovery voltage,  $V_{fr}$ , as a function of rate of change of current  $dI_F/dt$ .Fig.13. Typical reverse leakage current as a function of reverse voltage.  $I_R = f(V_R)$ ; parameter  $T_j$ Fig.11. Definition of forward recovery voltage  $V_{fr}$ Fig.14. Maximum thermal impedance  $Z_{th,j-mb}$  as a function of pulse width.

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### MECHANICAL DATA

*Dimensions in mm*

Net Mass: 2 g

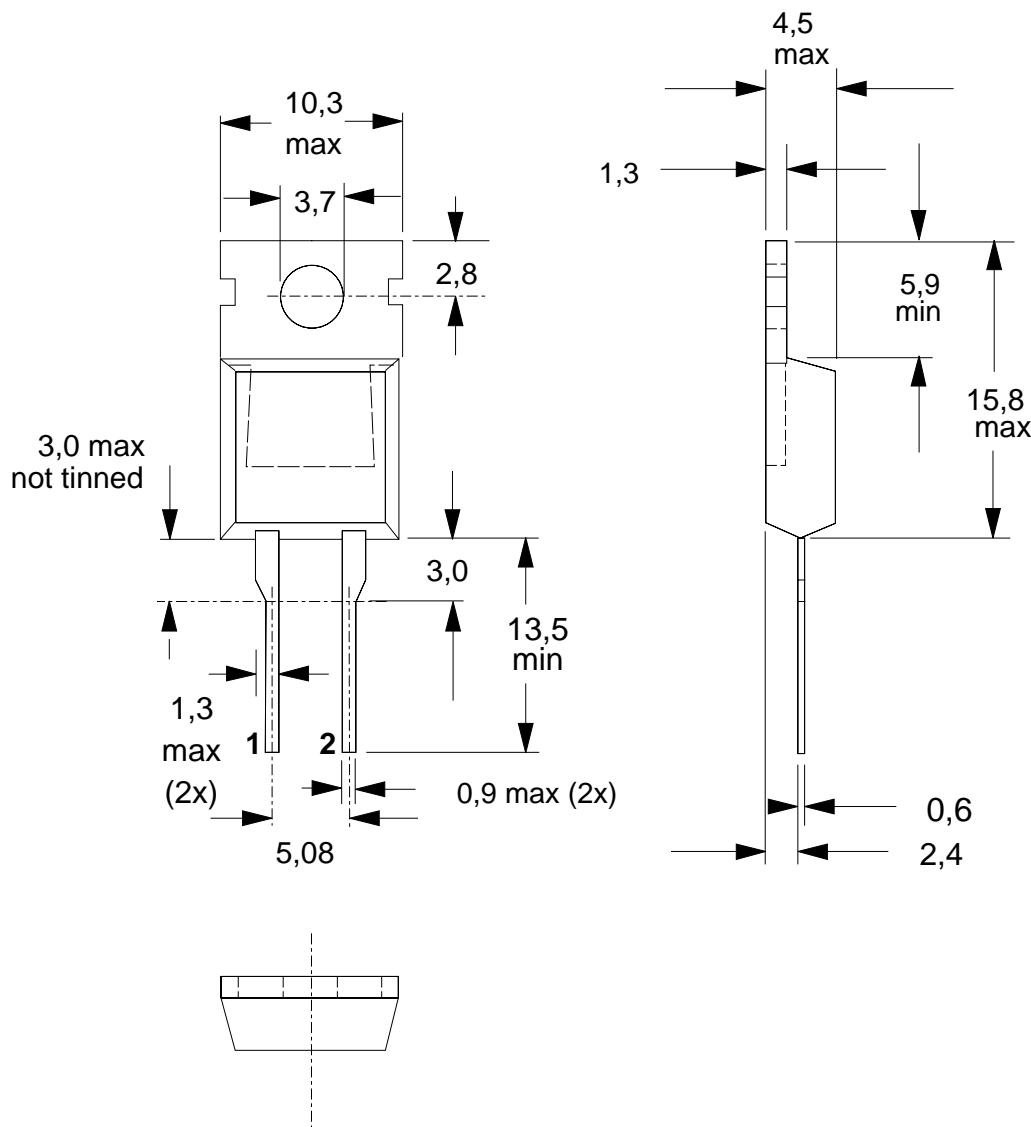


Fig.15. TO220AC; pin 1 connected to mounting base.

**Notes**

1. Refer to mounting instructions for TO220 envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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## DEFINITIONS

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
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